查询"MMBT4126"供应商 FAIRCHILD SEMICONDUCTOR TM 2N4126 **MMBT4126** С TO-92 С BE **SOT-23** R Mark: ZF

## **PNP General Purpose Amplifier**

This device is designed for general purpose amplifier and switching applications at collector currents to 10 µA as a switch and to 100 mA as an amplifier.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V	
V <sub>CBO</sub>	Collector-Base Voltage	25	V	
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V	
I <sub>C</sub>	Collector Current - Continuous	200	mA	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C	

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations. 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

#### **Thermal Characteristics**

Symbol	Characteristic	Max		Units	
		2N4126	*MMBT4126		
P <sub>D</sub>	Total Device Dissipation	625	350	mW	
	Derate above 25°C	5.0	2.8	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W	

TA= 25°C unless otherwise noted

\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

V<sub>CE(sat)</sub>

 $V_{\text{BE(sat)}}$ 

# **PNP General Purpose Amplifier**

0.4

0.95

V

V

(continued)

Electrical Characteristics TA=25°C unless otherwise noted					
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAF	RACTERISTICS				
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	25		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm E} = 0$	25		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	4.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, \text{ I}_{E} = 0$		50	nA
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		50	nA
		•			
ON CHAR	ACTERISTICS*				
h <sub>FE</sub>	DC Current Gain	$I_{C} = 2.0 \text{ mA}, V_{CE} = 1.0 \text{ V}$ $I_{C} = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	120 60	360	

 $I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$ 

 $I_{C} = 50 \text{ mA}, I_{B} = 5.0 \text{ mA}$ 

# SMALL SIGNAL CHARACTERISTICS

f⊤	Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	250		MHz
C <sub>ibo</sub>	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_C = 0,$ f = 1.0 MHz		10	pF
$C_{cb}$	Collector-Base Capcitance	$V_{CB} = 5.0 \text{ V}, I_E = 0,$ f = 100 kHz		4.5	pF
h <sub>fe</sub>	Small-Signal Current Gain	$I_{C} = 2.0 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 1.0 kHz	120	480	
NF	Noise Figure	$I_{c}$ = 100 μA, $V_{ce}$ = 5.0 V, R <sub>s</sub> =1.0 kΩ, f=10 Hz to 15.7 kHz		4.0	dB

\*Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

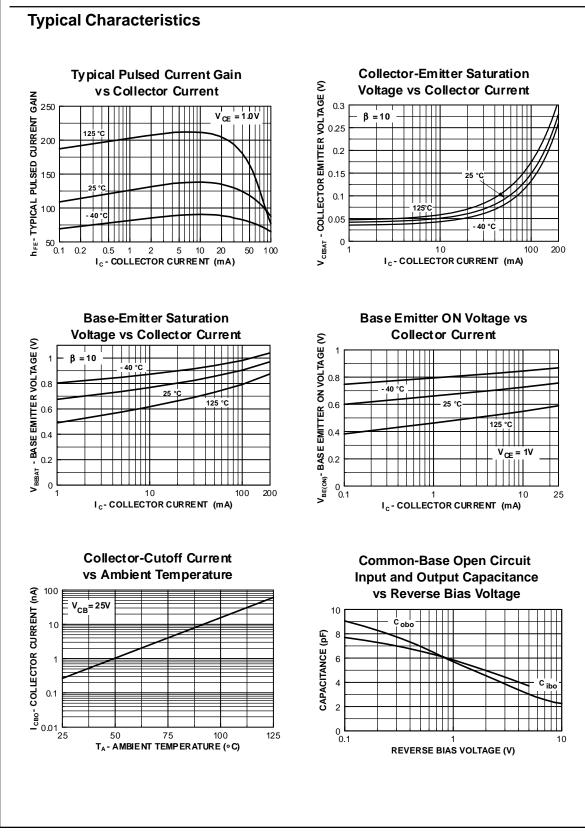
 $\textbf{NOTE:} \ \textbf{All voltages} \ (V) \ \textbf{and} \ \textbf{currents} \ (A) \ \textbf{are negative polarity for PNP transistors}.$ 

Collector-Emitter Saturation Voltage

Base-Emitter Saturation Voltage

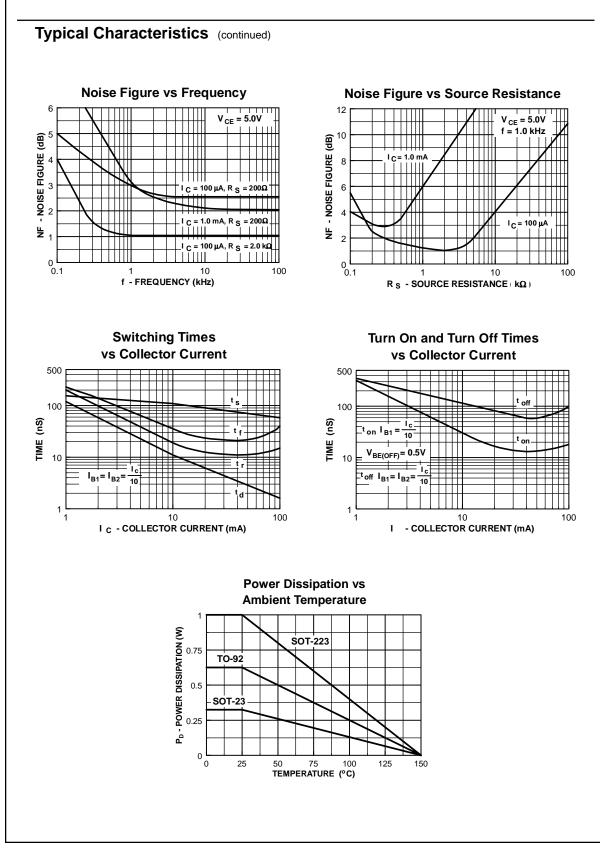
#### PNP General Purpose Amplifier (continued)

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# **PNP General Purpose Amplifier**

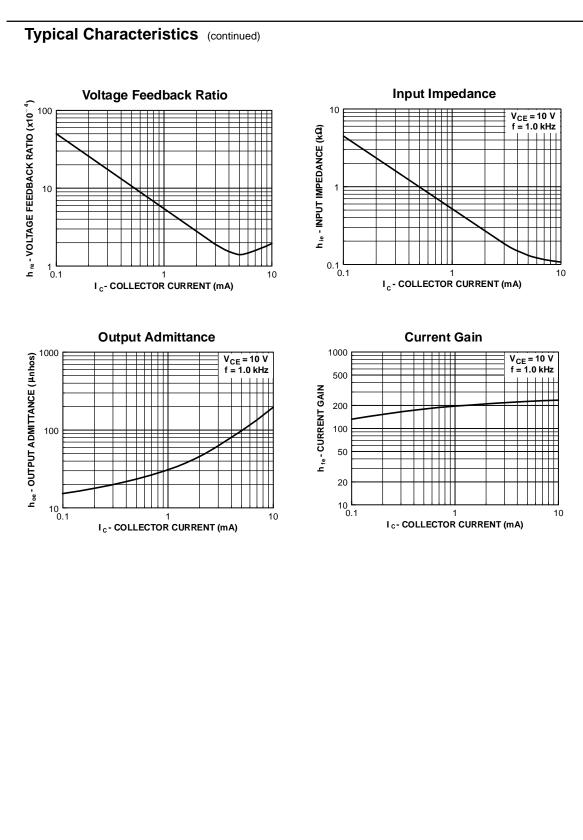
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# **PNP General Purpose Amplifier**

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